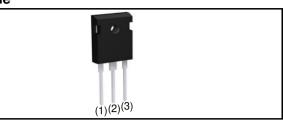


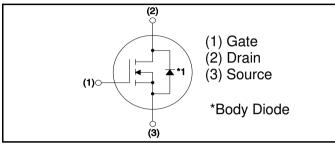
SCT3105KL N-channel SiC power MOSFET

V _{DSS}	1200V
R _{DS(on)} (Typ.)	105mΩ
I_{D}^{*1}	24A
P _D	134W

•Outline TO-247N



Inner circuit



Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

Application

- \cdot Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

Packaging specifications

	Packing	Tube
Туре	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3105KL

•Absolute maximum ratings (T_{vi} = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain - Source Voltage		V _{DSS}	1200	V
Continuous Drain current $T_c = 25^{\circ}C$		I _D ^{*1}	24	А
Continuous Drain current	$T_c = 100^{\circ}C$	I _D ^{*1}	17	А
Pulsed Drain current($T_c = 25^{\circ}C$)		I _{D,pulse} *2	60	А
Gate - Source voltage (DC)		V _{GSS}	-4 to +22	V
Gate - Source surge voltage (t _{surge} < 300nsec)		V _{GSS_surge} *3	-4 to +26	V
Recommended drive voltage		V _{GS_op} ^{*4}	0 / +18	V
Virtual Junction temperature		T _{vj}	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

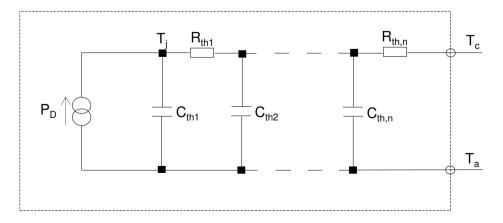
Parameter	Symbol	Conditions		Values		Unit	
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
		$V_{GS} = 0V, I_D = 1mA$					
Drain - Source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$T_{vj} = 25^{\circ}C$	1200	-	-	V	
		$T_{vj} = -55^{\circ}C$	1200	-	-		
		$V_{GS} = 0V, V_{DS} = 1200V$					
Zero Gate voltage Drain current	I_{DSS}	T _{vj} = 25°C	-	1	10	μA	
		T _{vj} = 150°C	-	2	-		
Gate - Source leakage current	I _{GSS+}	$V_{GS} = +22V$, $V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V , V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_{D} = 3.81mA$	2.7	-	5.6	V	
		$V_{GS} = 18V, I_{D} = 7.6A$					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *5	$T_{vj} = 25^{\circ}C$	-	105	137	mΩ	
		T _{vj} = 150°C	-	179	-		
Gate input resistance	R _G	f = 1MHz, open drain	-	13	-	Ω	

Thermal resistance

Parameter	Symbol		Values		Unit
	Symbol	Min.	Тур.	Max.	Onit
Thermal resistance, junction - case	R _{thJC}	-	0.86	1.12	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.08E-01		C _{th1}	4.72E-04	
R _{th2}	3.73E-01	K/W	C _{th2}	3.97E-03	Ws/K
R _{th3}	3.41E-01		C _{th3}	1.31E-02	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g _{fs} *5	$V_{DS} = 10V, I_{D} = 7.6A$	-	3.4	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	574	-	
Output capacitance	C _{oss}	V _{DS} = 800V	-	59	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	28	-	
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 600V	-	159	-	pF
Total Gate charge	Q_g^{*5}	$V_{DS} = 600V$ $I_{D} = 7.6A$	-	51	-	
Gate - Source charge	Q _{gs} *5	$V_{GS} = 18V$	-	10	-	nC
Gate - Drain charge	Q_{gd} *5	See Fig. 1-1.	-	25	-	
Turn - on delay time	t _{d(on)} *5	$V_{DS} = 400V$ $I_{D} = 7.6A$	-	17	-	
Rise time	t _r *5	V _{GS} = 0V/+18V	-	27	-	ns
Turn - off delay time	t _{d(off)} *5	$R_{G} = 0\Omega$ $R_{L} = 53\Omega$	-	31	-	115
Fall time	t _f *5	See Fig. 1-1, 1-2.	-	17	-	
Turn - on switching loss	E _{on} *5	$V_{DS} = 600V$ $V_{GS} = 0V/18V, I_D = 7.6A$ $R_G = 0\Omega, L = 750\mu H$	-	159	-	
Turn - off switching loss	E _{off} *5	E_{on} includes diode reverse recovery $L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 2-1, 2-2.	-	2	-	μJ



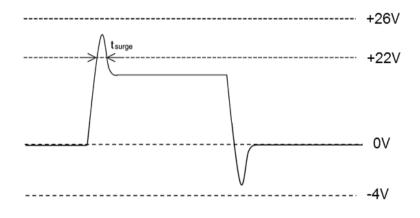
●Body diode electrical characteristics (Source-Drain) (T _{vi} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	Onit
Body diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	24	А
Body diode direct current, pulsed	I _{SM} *2	$T_{c} = 25 \text{ G}$	-	-	60	А
Forward voltage	V_{SD} *5	$V_{GS} = 0V, I_{S} = 7.6A$	-	3.2	-	V
Reverse recovery time	t _{rr} *5	$I_{\rm F} = 7.6 {\rm A}$ $V_{\rm B} = 600 {\rm V}$	-	15	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 1100A/µs	-	53	-	nC
Peak reverse recovery current	I _{rrm} *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 3-1, 3-2.	-	6.5	-	А

*1 Limited by maximum $T_{\nu j}$ and for Max. $R_{thJC}.$

*2 PW \leq 10µs, Duty cycle \leq 1%

*3 Example of acceptable V_{GS} waveform



- *4 Please be advised not to use SiC-MOSFETs with V_{GS} below 13V as doing so may cause thermal runaway.
- *5 Pulsed



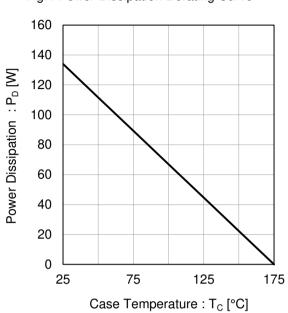
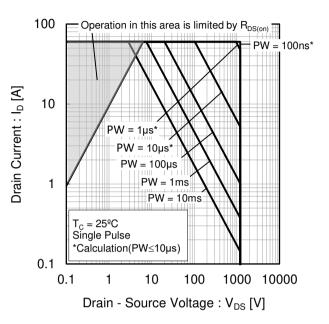
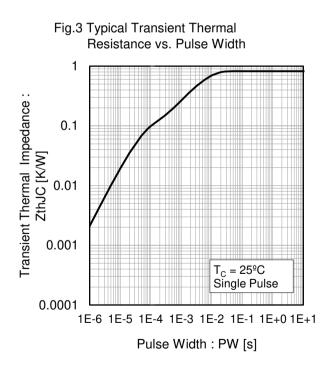


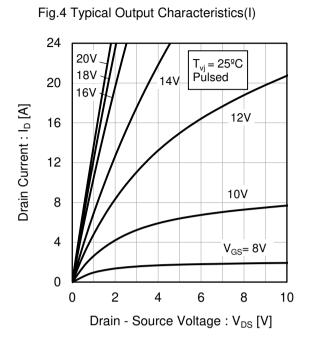
Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area









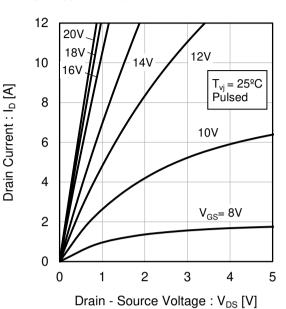
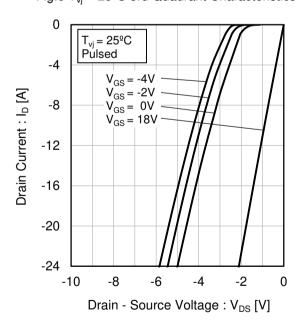


Fig.5 Typical Output Characteristics(II)

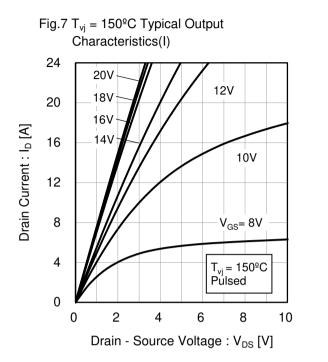
Fig.6 T_{vi} = 25°C 3rd Quadrant Characteristics





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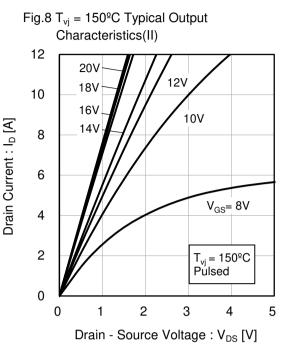


Fig.9 T_{vj} = 150ºC 3rd Quadrant Characteristics

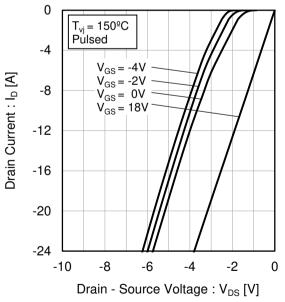
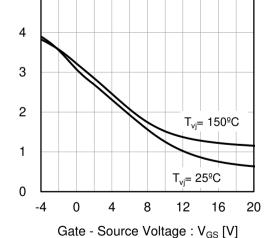
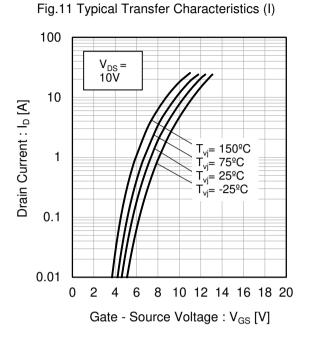


Fig.10 Body Diode Forward Voltage vs. Gate - Source Voltage



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Body Diode Forward Voltage : V_{SD} [V]



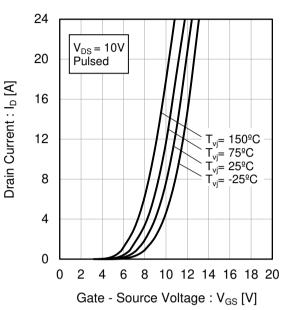


Fig.13 Gate Threshold Voltage vs. Junction Temperature 6 $V_{DS} = 10V$ Gate Threshold Voltage : V GS(th) [V] $I_{D} = 3.81 \text{mA}$ 5 4 3 2 1 0 -50 0 50 100 150 200 Junction Temperature : T_{vj} [ºC]

Fig.14 Transconductance vs. Drain Current

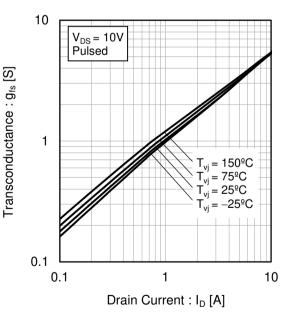
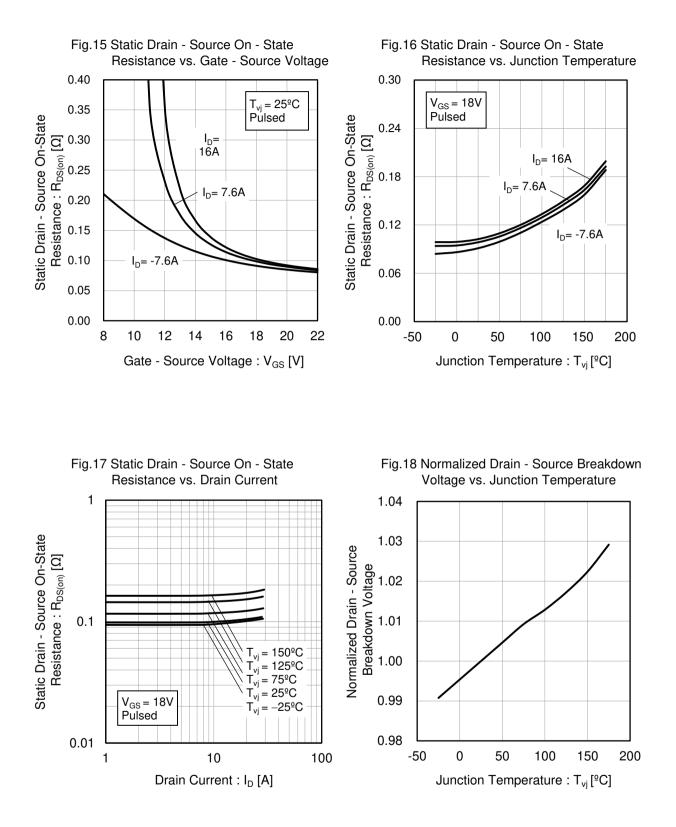


Fig.12 Typical Transfer Characteristics (II)







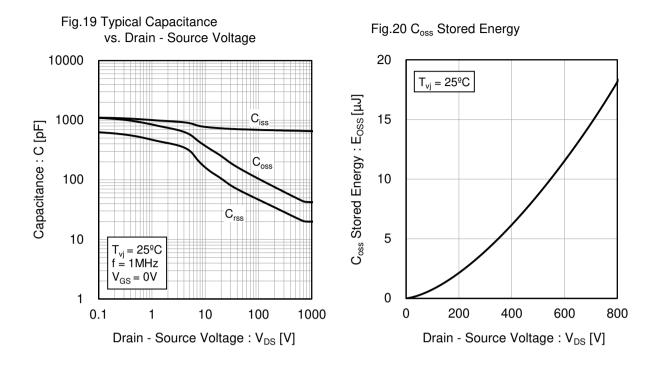
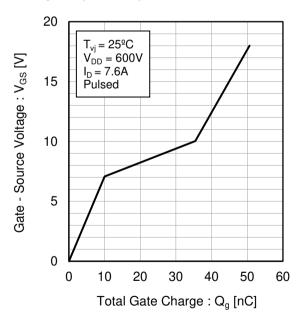
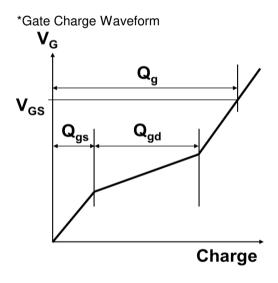
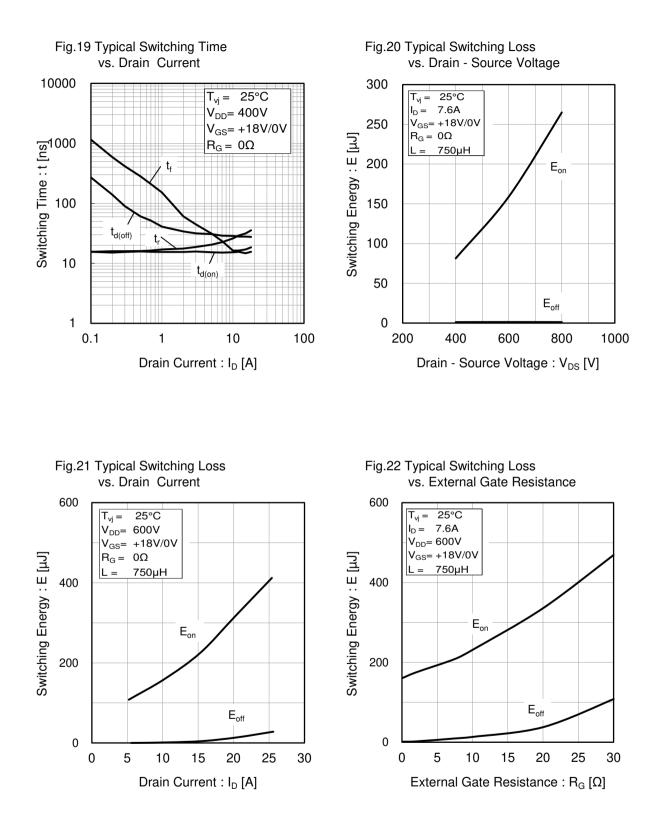


Fig.21 Dynamic Input Characteristics





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Measurement circuits and waveforms

Fig.1-1 Gate Charge and Switching Time Measurement Circuit

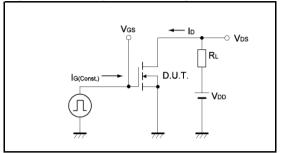


Fig.2-1 Switching Energy Measurement Circuit

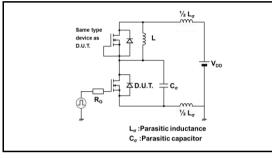


Fig.3-1 Reverse Recovery Time Measurement Circuit

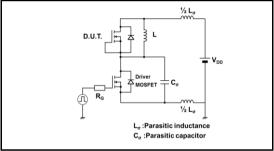


Fig.1-2 Waveforms for Switching Time

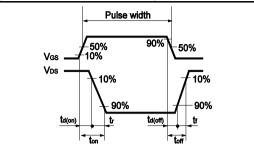


Fig.2-2 Waveforms for Switching Energy Loss

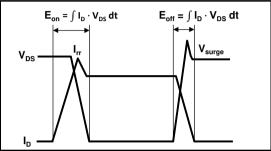
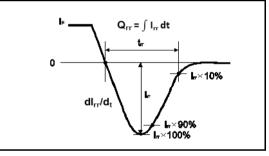
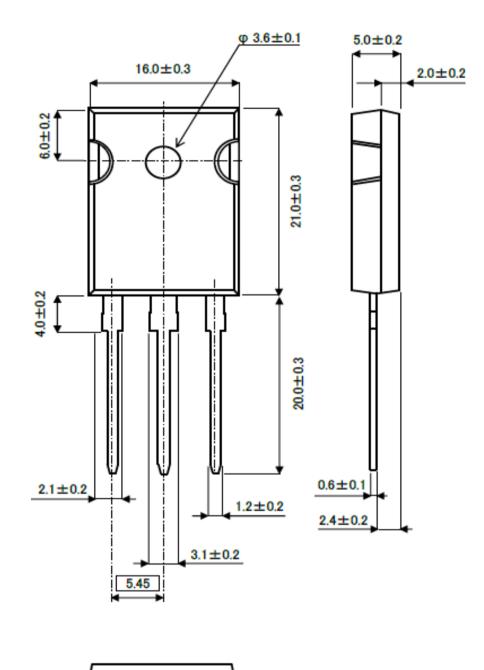


Fig.3-2 Reverse Recovery Waveform





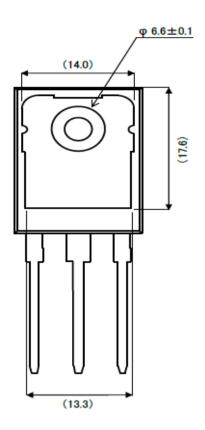
Package Dimensions





Unit: mm



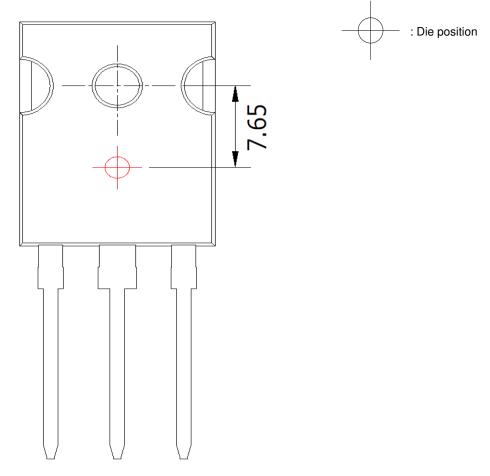


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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